

KSD1021

Audio Frequency Power Amplifier

Complement to KSB811
Collector Current : I_C=1A

• Collector Dissipation : P_C=350mW



1.Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	40	V
V _{CEO}	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	1	A
P _C	Collector Power Dissipation	350	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C=100\mu A, I_E=0$	40			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, I _B =0	30			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =100μA, I _C =0	5			V
I _{CBO}	Collector Cut-off Current	V_{CB} =30V, I_{E} =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =1V, I _C =100mA	70		400	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =1A, I _B =0.1A			0.5	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =1A, I _B =0.1A			1.2	V
f _T	Current Gain Band Width Product	V _{CE} =6V, I _C =10mA		130		MHz
C _{ob}	Output Capacitance	V _{CB} =6V, I _E =0, f=1MHz		16		pF

h_{FE} Classification

Classification	0	Y	G
h _{FE}	70 ~ 140	120 ~ 240	200 ~ 400

V_{CE} = 1V

Typical Characteristics

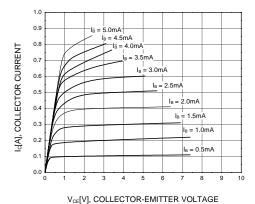
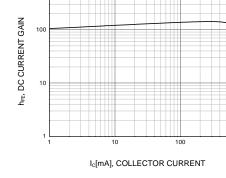


Figure 1. Static Characteristic



1000

Figure 2. DC current Gain

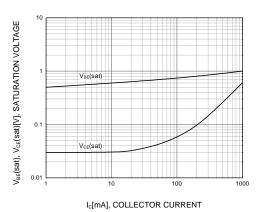


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

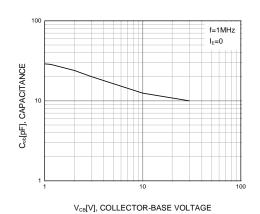


Figure 4. Collector Output Capacitance

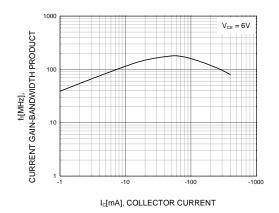


Figure 5. Current Gain Bandwidth Product

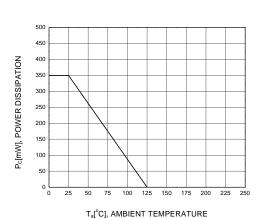
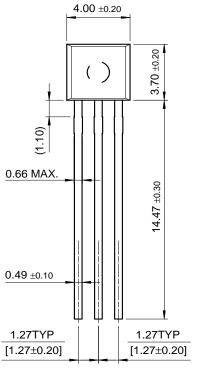


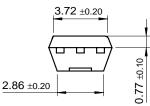
Figure 6. Power Derating

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Package Demensions

TO-92S







Dimensions in Millimeters

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